

PATENT ABSTRACTS OF JAPAN

(11)Publication number : 2002-100420
(43)Date of publication of application : 05.04.2002

(51)Int.CI. H01M 14/00
H01L 31/04

(21)Application number : 2000-290467 (71)Applicant : KONICA CORP
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(54) SEMICONDUCTOR FOR PHOTOELECTRIC TRANSFER MATERIAL OF SUPERIOR PHOTOELECTRIC TRANSFER EFFICIENCY AND DURABILITY, PHOTOELECTRIC TRANSFER ELEMENT, AND SOLAR BATTERY

(57)Abstract:

PROBLEM TO BE SOLVED: To provide a semiconductor for a photoelectric transfer material and a photoelectric transfer element, having superior photoelectric transfer efficiency compatible with safety, and to provide a solar battery, using this semiconductor for the photoelectric transfer material and the photoelectric transfer element.

SOLUTION: This semiconductor for the photoelectric transfer material has the feature that its sensitivity is increased by at least one kind of organic metal complex selected from among organic metallic complexes, having both an ionic coordinate bond formed by an nitrogen anion and an metal cation and a coordinate bond formed between a nitrogen atom or a chalcogen atom and the metal cation.

LEGAL STATUS

[Date of request for examination]

[Date of sending the examiner's decision of rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of rejection]

[Date of requesting appeal against examiner's decision of rejection]

[Date of extinction of right]

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